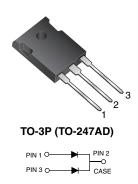


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## **Dual Common Cathode Ultrafast Plastic Rectifier**



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	30 A					
V <sub>RRM</sub>	50 V, 100 V, 150 V, 200 V					
I <sub>FSM</sub> 300 A						
t <sub>rr</sub> 25 ns						
V <sub>F</sub> at I <sub>F</sub>	0.85 V					
T <sub>J</sub> max. 150 °C						
Package	TO-3P (TO-247AD)					
Circuit configuration Common cathode						

### **FEATURES**

- Power pack
- Glass passivated pellet chip junction



- · Ultrafast recovery time
- · Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Solder dip 275 °C max., 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

### **MECHANICAL DATA**

Case: TO-3P (TO-247AD)

Molding compound meets UL 94V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	UG30APT	UG30BPT	UG30CPT	UG30DPT	UNIT		
Max. repetitive peak reverse voltage	V <sub>RRM</sub>	50	50 100 150 200		200	٧		
Max. RMS voltage	V <sub>RMS</sub>	35	35 70 105		140	٧		
Max. DC blocking voltage	V <sub>DC</sub>	50	100	150	200	٧		
Max. average forward rectified current at T <sub>C</sub> = 120 °C	I <sub>F(AV)</sub>	30						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	300				А		
Operating and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150				°C		



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDIT	TONS	SYMBOL	MBOL UG30APT UG30BPT UG30CPT UG30I			UG30DPT	UNIT
Max. instantaneous forward voltage per diode	15 A		V <sub>F</sub>	1.0				V
	30 A	T <sub>J</sub> = 100 °C		1.15				
ronago por aroao	10 A			0.85				
Max. DC reverse current at rated		T <sub>A</sub> = 25 °C		15				
DC blocking voltage per diode		T <sub>A</sub> = 100 °C	I <sub>R</sub>	800				μA
Max. reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	25				ns
M	$I_F = 15 \text{ A}, V_R = 30 \text{ V},$	T <sub>J</sub> = 25 °C		35				
Max. reverse recovery time	dl/dt = 50 A/µs, I <sub>RR</sub> = 10 % I <sub>RM</sub>	T <sub>J</sub> = 100 °C	t <sub>rr</sub>	50			ns	
Max. recovered stored charge	$I_F = 15 \text{ A}, V_R = 30 \text{ V},$	T <sub>J</sub> = 25 °C	0	22				0
	dl/dt = 50 A/µs, I <sub>RR</sub> = 10 % I <sub>RM</sub>	T <sub>J</sub> = 100 °C	Q <sub>rr</sub> 50				nC	
Typical junction capacitance	4.0 V, 1 MHz		CJ	70				pF

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER SYMBOL UG30APT UG30BPT UG30CPT UG30DPT						UNIT
Typical thermal resistance per diode (1)	$R_{\theta JC}$	2.0			°C/W	

### Note

<sup>(1)</sup> Thermal resistance from junction to case per diode mounted on heatsink

ORDERING INFORMATION (Example)								
PACKAGE	CKAGE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY							
TO-247AD	UG30DPT-E3/45	6.15	30	30/tube	Tube			



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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

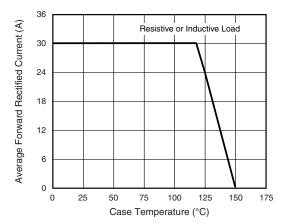


Fig. 1 - Max. Forward Current Derating Curve

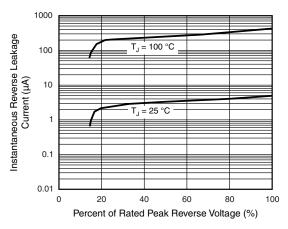


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

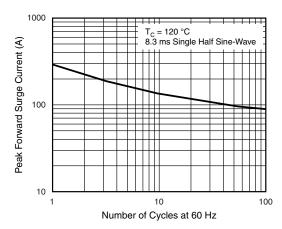


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

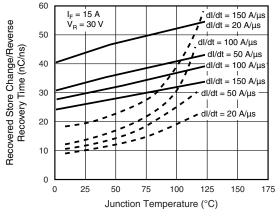


Fig. 5 - Reverse Switching Characteristics Per Diode

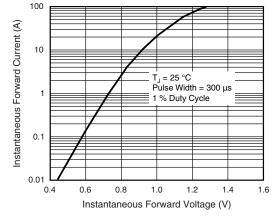


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

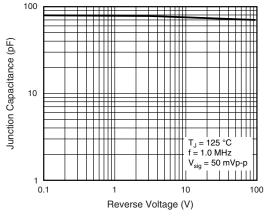


Fig. 6 - Typical Junction Capacitance Per Diode

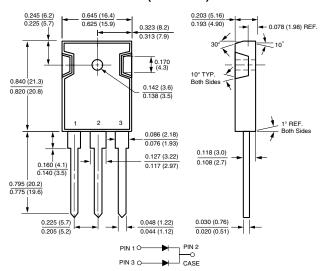


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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### TO-3P (TO-247AD)





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